



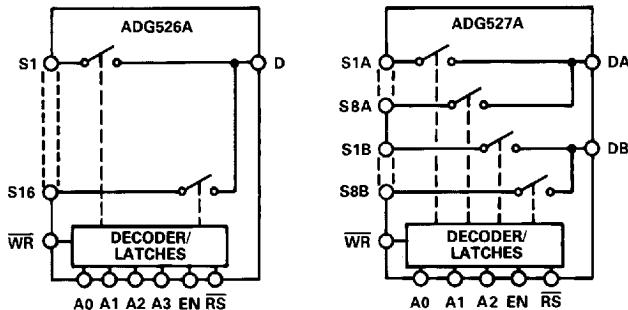
CMOS Latched 8/16 Channel Analog Multiplexers

ADG526A/ADG527A

FEATURES

44V Supply Maximum Rating
V_{SS} to V_{DD} Analog Signal Range
Single/Dual Supply Specifications
Wide Supply Ranges (10.8V to 16.5V)
Microprocessor Compatible (100ns WR Pulse)
Extended Plastic Temperature Range
(-40°C to +85°C)
Low Leakage (20pA typ)
Low Power Dissipation (28mW max)
Available in DIP, SOIC, PLCC and LCCC Packages
Superior Alternative to:
DG526
DG527

FUNCTIONAL BLOCK DIAGRAMS



GENERAL DESCRIPTION

The ADG526A and ADG527A are CMOS monolithic analog multiplexers with 16 channels and dual 8 channels respectively. On-chip latches facilitate microprocessor interfacing. The ADG526A switches one of 16 inputs to a common output depending on the state of four binary addresses and an enable input. The ADG527A switches one of 8 differential inputs to a common differential output depending on the state of three binary addresses and an enable input. Both devices have TTL and 5V CMOS logic compatible digital inputs.

The ADG526A and ADG527A are designed on an enhanced LC²MOS process which gives an increased signal capability of V_{SS} to V_{DD} and enables operation over a wide range of supply voltages. The devices can comfortably operate anywhere in the 10.8V to 16.5V single or dual supply range. These multiplexers also feature high switching speeds and low R_{ON}.

PRODUCT HIGHLIGHTS

1. Single/Dual Supply Specifications with a Wide Tolerance:
The devices are specified in the 10.8V to 16.5V range for both single and dual supplies.
2. Easily Interfaced:
The ADG526A and ADG527A can be easily interfaced with microprocessors. The WR signal latches the state of the Address control lines and the Enable line. The RS signal clears both the address and enable data in the latches resulting in no output (all switches off). RS can be tied to the microprocessor reset pin.
3. Extended Signal Range:
The enhanced LC²MOS processing results in a high breakdown and an increased analog signal range of V_{SS} to V_{DD}.
4. Break-Before-Make Switching:
Switches are guaranteed break-before-make so that input signals are protected against momentary shorting.
5. Low Leakage:
Leakage currents in the range of 20pA make these multiplexers suitable for high precision circuits.

REV. A

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ADG526A/ADG527A

TIMING DIAGRAMS

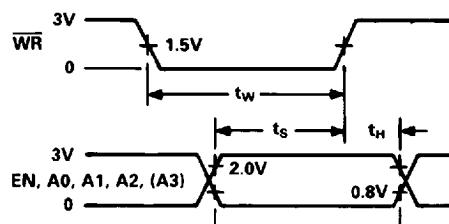


Figure 1.

Figure 1 shows the timing sequence for latching the switch address and enable inputs. The latches are level sensitive; therefore, while \overline{WR} is held low, the latches are transparent and the switches respond to the address and enable inputs. This input data is latched on the rising edge of \overline{WR} .

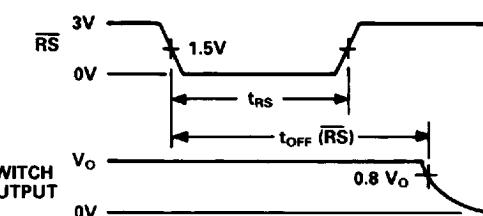


Figure 2.

Figure 2 shows the Reset Pulse Width, t_{RS} , and Reset Turn-off Time, $t_{OFF}(\overline{RS})$.

Note: All digital input signals rise and fall times measured from 10% to 90% of 3V. $t_R = t_F = 20\text{ns}$.

ABSOLUTE MAXIMUM RATINGS*

($T_A = +25^\circ\text{C}$ unless otherwise noted)

V_{DD} to V_{SS}	44V
V_{DD} to GND	25V
V_{SS} to GND	-25V
Analog Inputs ¹	
Voltage at S, D	$V_{SS} - 2\text{V}$ to $V_{DD} + 2\text{V}$ or 20mA, Whichever Occurs First
Continuous Current, S or D	20mA
Pulsed Current S or D	
1ms Duration, 10% Duty Cycle	40mA
Digital Inputs ¹	
Voltage at A, EN, \overline{WR} , \overline{RS}	$V_{SS} - 4\text{V}$ to $V_{DD} + 4\text{V}$ or 20mA, Whichever Occurs First
Power Dissipation (Any Package)	
Up to $+75^\circ\text{C}$	470mW
Derates above $+75^\circ\text{C}$ by	6mW/ $^\circ\text{C}$

CAUTION:

ESD (electrostatic discharge) sensitive device. The digital control inputs are diode protected; however, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are inserted.



ORDERING GUIDE

Model ¹	Temperature Range	Package Option ²
ADG526AKN	-40°C to +85°C	N-28
ADG526AKR	-40°C to +85°C	R-28
ADG526AKP	-40°C to +85°C	P-28A
ADG526ABQ	-40°C to +85°C	Q-28
ADG526ATQ ³	-55°C to +125°C	Q-28
ADG526ATE ³	-55°C to +125°C	E-28A
ADG527AKN	-40°C to +85°C	N-28
ADG527AKR	-40°C to +85°C	R-28
ADG527AKP	-40°C to +85°C	P-28A
ADG527ABQ	-40°C to +85°C	Q-28
ADG527ATQ ³	-55°C to +125°C	Q-28
ADG527ATE ³	-55°C to +125°C	E-28A

NOTES

¹To order MIL-STD-883, Class B processed parts, add /883B to part number. See Analog Devices Military Products Databook (1990) for military data.

²E = Leadless Ceramic Chip Carrier; N = Narrow Plastic DIP; P = Plastic Leaded Chip Carrier; Q = Cerdip; R = 0.3" Small Outline IC (SOIC).

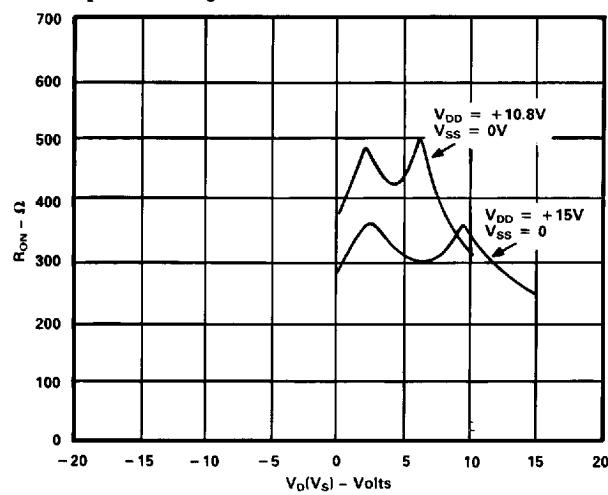
³Standard Military Drawing (SMD) assigned by DESC. SMD numbers are

- 5962-89710013X (ADG526ATE/883B)
- 5962-8971001XX (ADG526ATQ/883B)
- 5962-89710023X (ADG527ATE/883B)
- 5962-8971002XX (ADG527ATQ/883B)

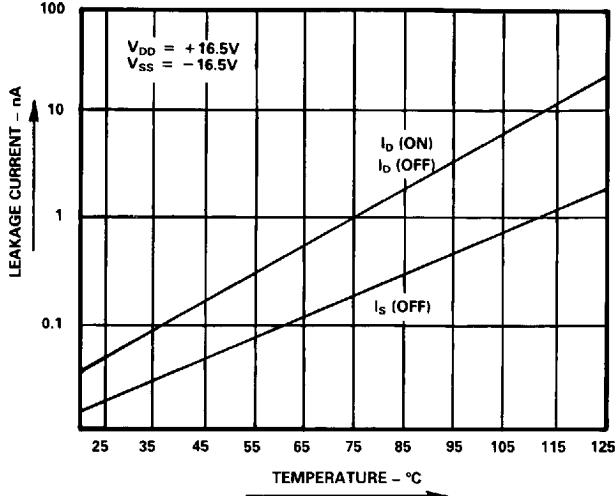
ADG526A/ADG527A

Typical Performance Characteristics

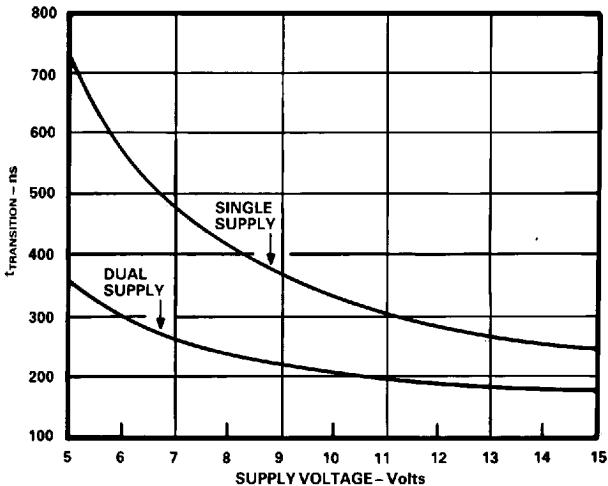
The multiplexers are guaranteed functional with reduced single or dual supplies down to 4.5V.



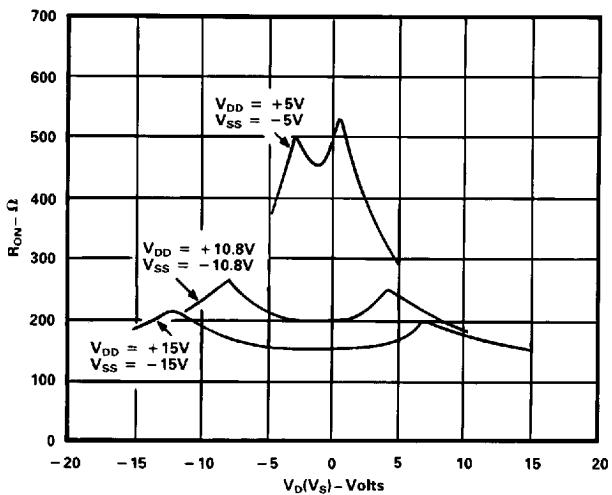
R_{ON} as a Function of $V_D(V_S)$: Dual Supply Voltage,
 $T_A = +25^\circ C$



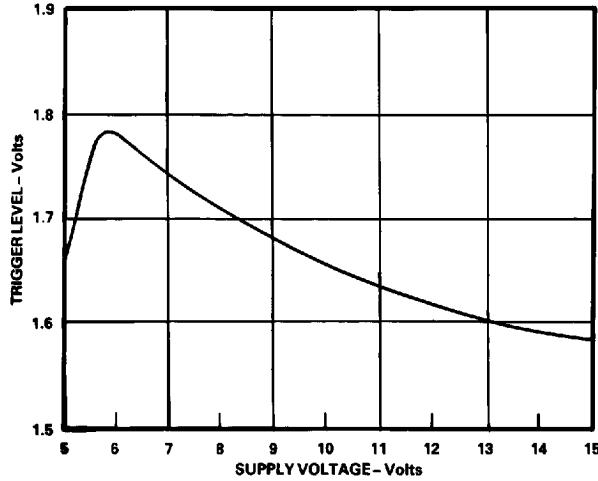
Leakage Current as a Function of Temperature
(Note: Leakage Currents Reduce as the Supply Voltages Reduce)



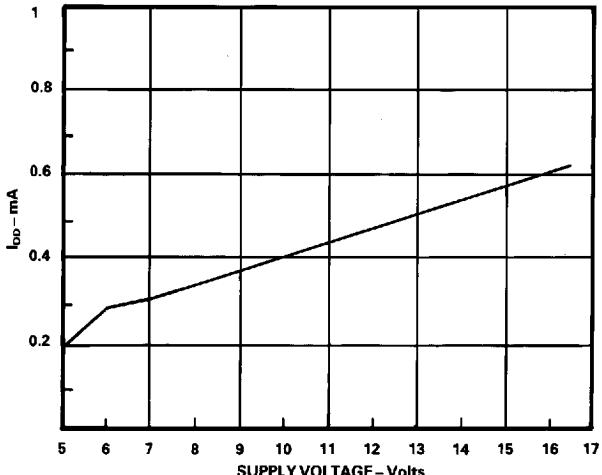
$t_{TRANSITION}$ vs. Supply Voltage: Dual and Single Supplies,
 $T_A = +25^\circ C$
(Note: For V_{DD} and $|V_{SS}| < 10V$; $V1 = V_{DD}/V_{SS}$,
 $V2 = V_{SS}/V_{DD}$. See Test Circuit 6)



R_{ON} as a Function of $V_D(V_S)$: Single Supply Voltage,
 $T_A = +25^\circ C$



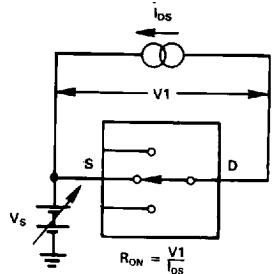
Trigger Levels vs. Power Supply Voltage, Dual or Single Supply, $T_A = +25^\circ C$



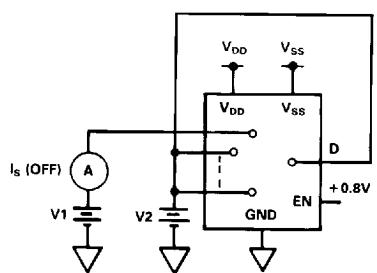
I_{DD} vs. Supply Voltage: Dual or Single Supply, $T_A = +25^\circ C$

Test Circuits—ADG526A/ADG527A

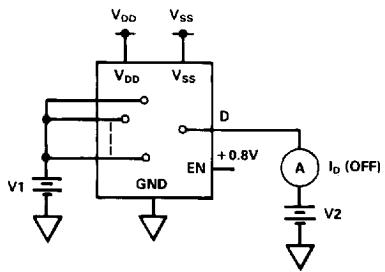
TEST CIRCUIT 1 R_{ON}



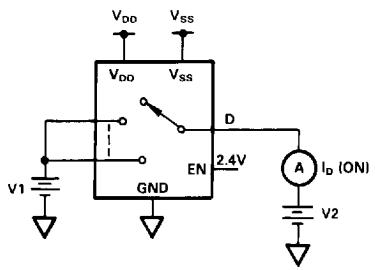
TEST CIRCUIT 2 $I_s(\text{OFF})$



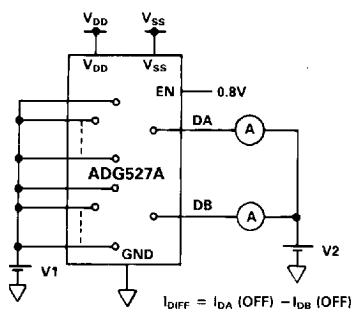
TEST CIRCUIT 3 $I_D(\text{OFF})$



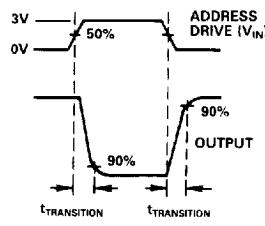
TEST CIRCUIT 4 $I_D(\text{ON})$



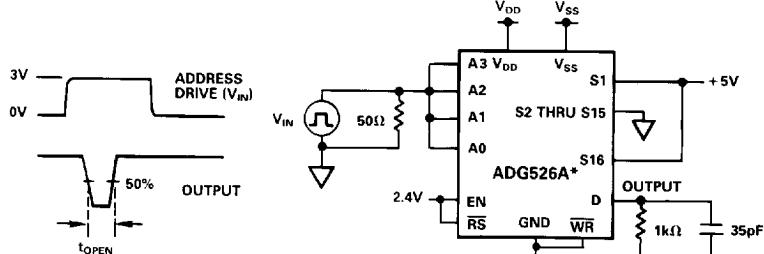
TEST CIRCUIT 5 I_{DIFF}



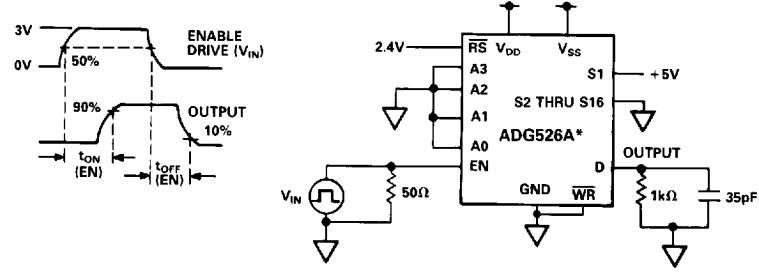
TEST CIRCUIT 6 SWITCHING TIME OF MULTIPLEXER, $t_{\text{TRANSITION}}$



TEST CIRCUIT 7 BREAK-BEFORE-MAKE DELAY, t_{OPEN}

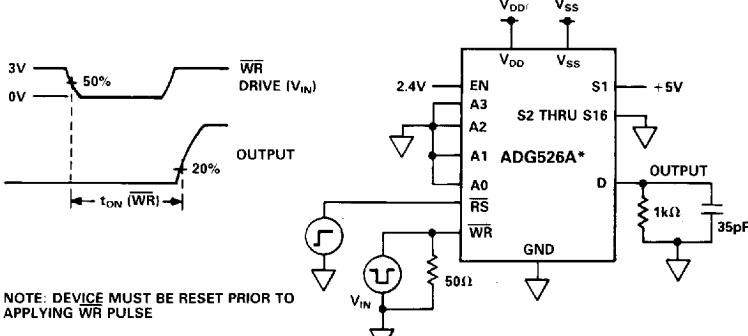


TEST CIRCUIT 8 ENABLE DELAY, $t_{\text{ON}}(\text{EN})$, $t_{\text{OFF}}(\text{EN})$



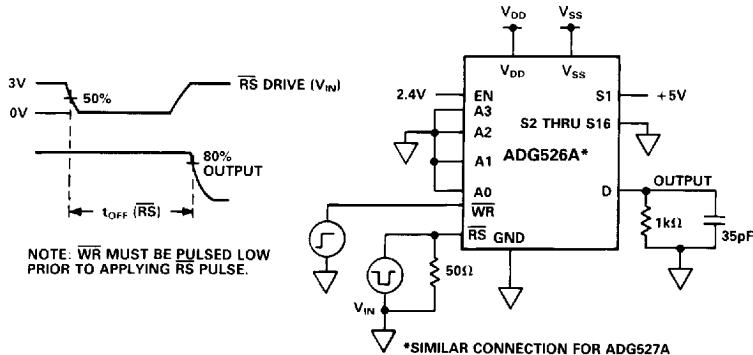
*SIMILAR CONNECTION FOR ADG527A

TEST CIRCUIT 9 WRITE TURN-ON TIME, $t_{\text{ON}}(\overline{\text{WR}})$



*SIMILAR CONNECTION FOR ADG527A

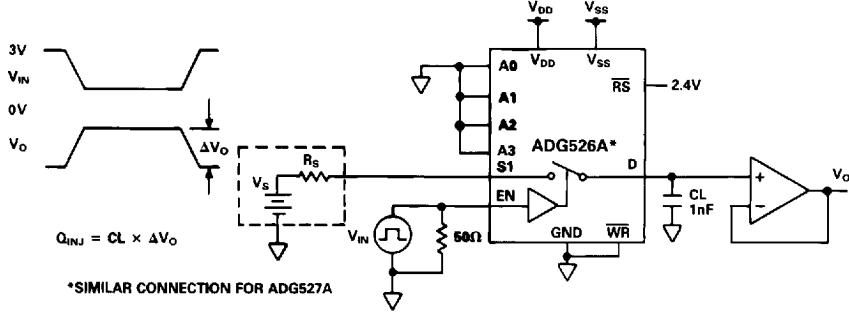
TEST CIRCUIT 10 RESET TURN-OFF TIME, $t_{\text{OFF}}(\overline{\text{RS}})$



*SIMILAR CONNECTION FOR ADG527A

ADG526A/ADG527A

TEST CIRCUIT 11 CHARGE INJECTION



TERMINOLOGY

R _{ON}	Ohmic resistance between terminals D and S
R _{ON} Match	Difference between the R _{ON} of any two channels
R _{ON} Drift	Change in R _{ON} versus temperature
I _S (OFF)	Source terminal leakage current when the switch is off
I _D (OFF)	Drain terminal leakage current when the switch is off
I _D (ON)	Leakage current that flows from the closed switch into the body
V _S (V _D)	Analog voltage on terminal S or D
C _s (OFF)	Channel input capacitance for "OFF" condition
C _D (OFF)	Channel output capacitance for "OFF" condition
C _{IN}	Digital input capacitance
t _{ON} (EN)	Delay time between the 50% and 90% points of the digital input and switch "ON" condition

t_{OFF} (EN)

Delay time between the 50% and 10% points of the digital input and switch "OFF" condition

t_{TRANSITION}

Delay time between the 50% and 90% points of the digital inputs and switch "ON" condition when switching from one address state to another

t_{OPEN}

"OFF" time measured between 50% points of both switches when switching from one address state to another

V_{INL}

Maximum input voltage for Logic "0"

V_{INH}

Minimum input voltage for Logic "1"

I_{INL} (I_{INH})

Input current of the digital input

V_{DD}

Most positive voltage supply

V_{SS}

Most negative voltage supply

I_{DD}

Positive supply current

I_{SS}

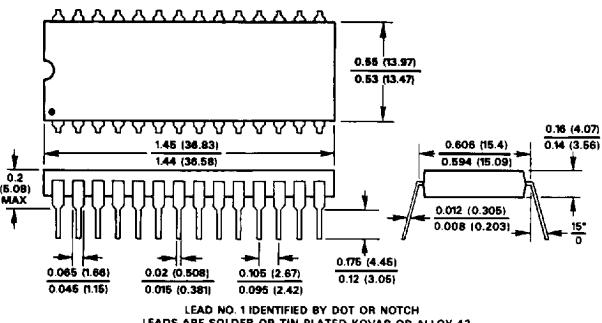
Negative supply current

MECHANICAL INFORMATION

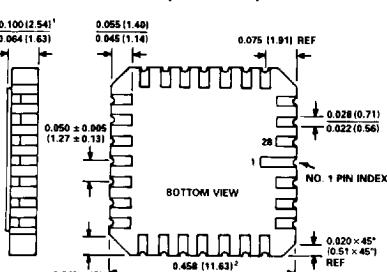
OUTLINE DIMENSIONS

Dimension shown in inches and (mm).

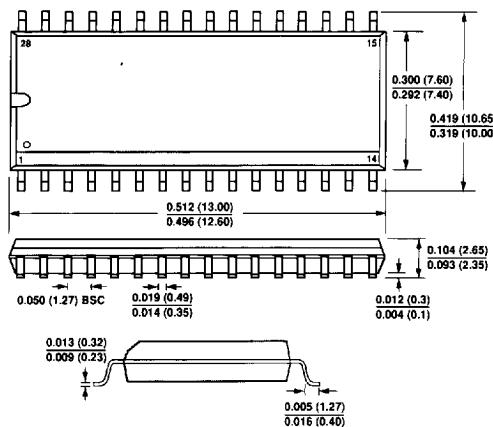
28-Pin Plastic DIP (Suffix N)



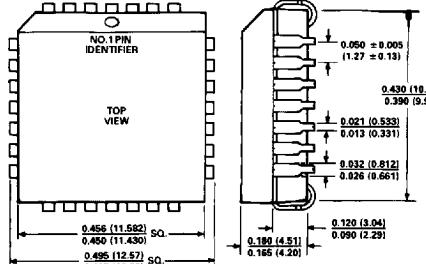
28-Terminal Leadless Ceramic Chip Carrier (Suffix E)



28-Pin SOIC (R) Package



28-Terminal Plastic Leaded Chip Carrier (Suffix P)



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